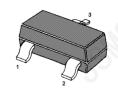


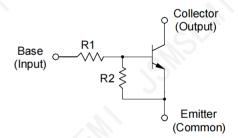
for switching and interface circuit and drive circuit applications



1.Base 2.Emitter 3.Collector
SOT-23 Plastic Package

#### **Resistor Values**

Туре	R1 (K)	R2 (K)
PDTC123JT,215-JSM	4.7	47



### Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V <sub>CBO</sub>	50	V
Collector Emitter Voltage	V <sub>CEO</sub>	50	V
Collector Current	Ic	100	mA
Total Power Dissipation	P <sub>tot</sub>	200	mW
Junction Temperature	Tj	150	°C
Storage Temperature Range	Ts	- 55 to + 150	°C



### Characteristics at Ta = 25 °C

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE}$ = 10 V, $I_C$ = 5 mA	h <sub>FE</sub>	80	- 3	-
Collector Base Cutoff Current at V <sub>CB</sub> = 50 V	I <sub>CBO</sub>	-	100	nA
Collector Emitter Cutoff Current at V <sub>CE</sub> = 50 V	I <sub>CEO</sub>	61111	500	nA
Emitter Base Cutoff Current at V <sub>EB</sub> = 6 V	I <sub>EBO</sub>	٥ -	0.18	mA
Collector Base Breakdown Voltage at $I_C = 10 \mu A$	V <sub>(BR)CBO</sub>	50	-	V
Collector Emitter Breakdown Voltage at I <sub>C</sub> = 2 mA	V <sub>(BR)CEO</sub>	50	- 0	V
Collector Emitter Saturation Voltage at $I_C = 10$ mA, $I_B = 0.3$ mA at $I_C = 10$ mA, $I_B = 5$ mA at $I_C = 10$ mA, $I_B = 1$ mA	V	_ 🖒	0.05	V
at ic = 10 mA, iB = 1 mA	VCEsat		0.25	V

# Characteristics at T<sub>a</sub> = 25 °C

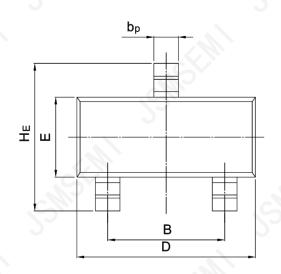
Parameter	Symbol	Min.	Max.	Unit
Output Voltage (on) at $V_{CC}$ = 5 V, $V_B$ = 2.5 V, $R_L$ = 1 K $\Omega$ at $V_{CC}$ = 5 V, $V_B$ = 3.5 V, $R_L$ = 1 K $\Omega$	3/13		Ç.	
at $V_{CC} = 5 \text{ V}$ , $V_B = 5 \text{ V}$ , $R_L = 1 \text{ K}\Omega$	V <sub>OL</sub>	-	0.2	V
Output Voltage (off) at $V_{CC}$ = 5 V, $V_B$ = 0.5 V, $R_L$ = 1 K $\Omega$ at $V_{CC}$ = 5 V, $V_B$ = 0.05 V, $R_L$ = 1 K $\Omega$ at $V_{CC}$ = 5 V, $V_B$ = 0.25 V, $R_L$ = 1 K $\Omega$	V <sub>OH</sub>	4.9	<u>.</u>	V
Input Resistor	R1	15.4	28.6	ΚΩ
Resistor Ratio	R1/R2	0.055	0.185	

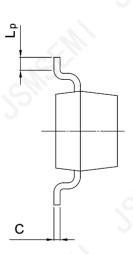


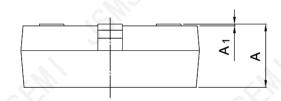
### **PACKAGE OUTLINE**

### Plastic surface mounted package; 3 leads

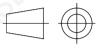
**SOT-23** 







mm	UNIT	Α	В	bp	С	D	E	HE	A1	Lp
	mm	I	l					l		0.50 0.20





## **Revision History**

Rev.	Change	Date
V1.0	Initial version	2/23/2024
-11		

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